Vibrational Excitations of Solitons in Polyacetylene

Mele and Rice¹ have recently shown that charged solitons in the Peierls model of polyacetylene lead to infrared-active modes within the semiconductor gap. They suggest that the experimentally observed² modes at 900 and 1370 cm⁻¹ result from two vibrational normal modes while the oscillation of the soliton pinned to an ionized impurity yields a mode at a much lower frequency. Fincher *et al.*,² however, claimed that the 900-cm⁻¹ mode is the pinned mode since its width is unusually large (~400 cm⁻¹).

I have carried out the same calculation within the continuum model.³ Consider the charge with a dimerization amplitude $\Delta(x - \varphi(t))$, i.e., its position is a time-dependent field. At frequencies low compared with the gap $2\Delta_0$ this leads to a current $j(t) = e\rho \partial \varphi / \partial t$ where ρ is the charge density.

Each phonon has an order parameter $\Delta_n(x-\varphi_n(t))$ $(n=1, 2, \ldots, N)$ with $\varphi_n(t)$ its oscillation degree of freedom. In the ground state³ $\Delta_n(x) = \Delta(x)\lambda_n/\lambda$ where λ_n is the dimensionless electron-phonon coupling and $\lambda = \sum_n \lambda_n$. After expansion $\Delta(x-\varphi)$ $= \sum_n \Delta_n(x-\varphi_n)$ the translation mode φ is identified as $\varphi = \sum_n \varphi_n \lambda_n/\lambda$. The effective Lagrangian to second order in φ_n is

$$L_{eff} = \frac{1}{2} M_s \Omega_0^2 \Big\{ \sum_n \left[-\varphi_n^2 + \left(\frac{\dot{\varphi}_n}{\omega_n^0}\right)^2 \right] \frac{\lambda_n}{\lambda} + (1-\alpha)\varphi^2 \Big\}, \qquad (1)$$

where $M_s = 4\Delta_0^{3/}(3\pi\lambda\Omega_0^2 v_F^2)$ is the soliton kinetic mass, $\Omega_0^{-2} = \sum_n \lambda_n / \lambda (\omega_n^{0})^2$, ω_n^{0} are the bare phonon frequencies, and α represents pinning to an ionized impurity. The φ^2 term in (1) comes from the electron-phonon interaction and if $\alpha = 0$ it reduces the translation mode frequency to zero.

Adding to (1) the coupling of j(t) to an electric field leads to a set of equations of motion for $\varphi_n(t)$ which determine $\varphi(t)$ and the conductivity

$$\sigma(\omega) = e^{2}i\omega\rho M_{s}^{-1}\Omega_{0}^{-2}D_{0}(\omega)/[1+(1-\alpha)D_{0}(\omega)],$$
(2)

where $D_0(\omega) = \sum_n [(\omega/\omega_n^0)^2 - 1]^{-1} \lambda_n / \lambda$.

For $\alpha = 0$ Eq. (2) yields the Fröhlich type superconductivity with an oscillator strength $\pi \rho / M_s$. For $\alpha \neq 0$ this sliding mode appears at a finite frequency. For two or more phonons additional peaks in $\operatorname{Re}\sigma(\omega)$ appear at ω_n^{φ} , one in each interval $(\omega_n^{0}, \omega_{n+1}^{0})$, just as in the incommensurate limit of the Peierls model.^{4,5}

Note that the number of ω_n^{φ} modes, *including* the sliding mode, equals the number N of bare modes. Reference 1 suggests that there are three ω_n^{φ} modes which means that there must be another coupled vibration in addition to the two modes in their Fig. 3.

However, if the mode at 900 cm⁻¹ is not the pinned mode, then 900 cm⁻¹ > ω_1^0 which is inconsistent with both Fig. 1(a) of Ref. 1 and with experimental data, as I show next.

Since ω_n^0 is not available experimentally I use the Raman frequencies ω_n^R which correspond to amplitude oscillations. The calculation is the same as in the incommensurate case⁵ except $\lambda - 2\lambda$.³ For $\omega \ll 2\Delta_0 \omega_n^R$ satisfy $1 = (2\lambda - 1)D_0(\omega)$; thus $\omega_1^R < \omega_1^0$ and the other modes are in the intervals $(\omega_n^0, \omega_{n+1}^0)$. Experimentally⁶ the lowest frequency Raman mode is at ~1075 cm⁻¹ (or the very weak mode at 1015 cm⁻¹); thus ω_1^0 is at a higher frequency and the 900-cm⁻¹ mode cannot be but the pinned mode.

The data thus support a two-phonon system: $\omega_1^{\varphi} = 900 \text{ cm}^{-1}$ as the pinned mode and $\omega_2^{\varphi} = 1370 \text{ cm}^{-1}$. With use of $2\lambda = 0.38$, ${}^{3}\omega_1^{R} = 1075 \text{ cm}^{-1}$ and $\omega_2^{R} = 1470 \text{ cm}^{-1}$, 6 the equations for ω_n^{φ} and ω_n^{R} yield $\omega_1^{0} = 1210 \text{ cm}^{-1}$, $\omega_2^{0} = 2110 \text{ cm}^{-1}$, $\lambda_1/\lambda = 0.08$, $\lambda_2/\lambda = 0.92$, and $\alpha = 0.23$. The intensity ratio of ω_1^{φ} to ω_2^{φ} modes is 2.3 in good agreement with experimental data. The dielectric constant $\epsilon(0) = 1 + 4\pi\rho e^2/\alpha M_s \Omega_0^2$ can now be used to determine M_s , the single parameter in the theory which contains the identity of the charge carrier.

Baruch Horovitz

Department of Nuclear Physics The Weizmann Institute of Science Rehovot 76100, Israel

Received 29 May 1980

PACS numbers: 72.15.Nj, 78.30.Jw, 63.20.Dj, 78.50.-w

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